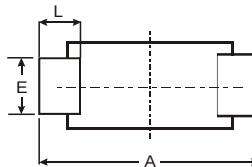
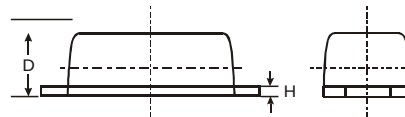
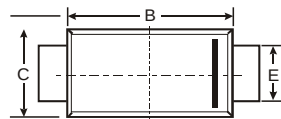


Features

- Glass passivated chip
- Maximum 400 W peak pulse power capability with a 10/1000 us waveform, rate(duty cycle):0.01%
- Low leakage
- Uni polar unit
- Excellent clamping capability
- Very fast response time

Mechanical Data

- Case: SOD-123FL
plastic body over passivated junction
- Terminals : Plated axial leads,
- solderable per MIL-STD-750, Method 2026
- Polarity : Color band denotes cathode end
- Mounting Position : Any
- Weight:0.0007 ounce, 0.02 grams



SOD-123FL			
Dim	Min	Max	Typ
A	3.50	3.80	3.65
B	2.60	2.90	2.75
C	1.70	1.90	1.80
D	0.09	1.10	1.00
E	0.08	1.10	0.095
H	0.12	0.20	0.16
L	0.07	0.09	0.08
All Dimensions in mm			

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbol	Value	Unit
Peak power dissipation with a 10/1000μs waveform ⁽¹⁾⁽³⁾	P _{PP}	400	W
Peak pulse current with a 10/1000μs waveform ⁽¹⁾	I _{PP}	See Next Table	A
Power dissipation on infinite heatsink at T _L = 75 °C	P _D	1.0	W
Peak forward surge current, 8.3 ms single half sine-wave unidirectional ⁽²⁾	I _{FSM}	30	A
Maximum instantaneous forward voltage at 25 A for unidirectional only	V _F	3.5	V
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150	°C

Note:

(1)Non-repetitive current pulse per Fig.3 and derated above T_A = 25 °C per Fig. 1.

(2)Measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum.

Electrical Characteristics (TA=25°C unless otherwise noted)

TYPE (UNI)	Reverse Stand-Off Voltage	Breakdown Voltage Min. @ I _T	Breakdown Voltage Max. @ I _T	Test Current	Reverse Leakage @ V _{RWM}	Peak Pulse Current	Maximum Clamping Voltage @ I _{PP}
	V _{RWM} (V)	V _{BR MIN} (V)	V _{BR MAX} (V)	I _T (mA)	I _R (uA)	I _{PP} (A)	V _C (V)
TPSMF4L5.0A	5.0	6.40	7.00	10	800	40.10	9.20
TPSMF4L6.0A	6.0	6.67	7.37	10	800	35.90	10.30
TPSMF4L6.5A	6.5	7.22	7.98	10	500	33.10	11.20
TPSMF4L7.0A	7.0	7.78	8.60	10	200	30.90	12.00
TPSMF4L7.5A	7.5	8.33	9.21	10	100	28.70	12.90
TPSMF4L8.0A	8.0	8.89	9.83	1	50	27.20	13.60
TPSMF4L8.5A	8.5	9.44	10.40	1	20	25.70	14.40
TPSMF4L9.0A	9.0	10.00	11.10	1	10	24.10	15.40
TPSMF4L10A	10	11.10	12.30	1	5	23.50	17.00
TPSMF4L11A	11	12.20	13.50	1	1	22.00	18.20
TPSMF4L12A	12	13.30	14.70	1	1	20.10	19.90
TPSMF4L13A	13	14.40	15.90	1	1	18.60	21.50
TPSMF4L14A	14	15.80	17.20	1	1	17.20	23.20
TPSMF4L15A	15	18.70	18.50	1	1	16.40	24.40
TPSMF4L16A	16	17.80	19.70	1	1	15.40	26.00
TPSMF4L17A	17	18.90	20.90	1	1	14.50	27.60
TPSMF4L18A	18	20.00	22.10	1	1	13.70	29.20
TPSMF4L20A	20	22.20	24.50	1	1	12.30	32.40
TPSMF4L22A	22	24.40	26.90	1	1	11.30	35.50
TPSMF4L24A	24	26.70	29.50	1	1	10.30	38.90
TPSMF4L26A	26	28.90	31.90	1	1	9.50	42.10
TPSMF4L28A	28	31.10	34.40	1	1	8.80	45.40
TPSMF4L30A	30	33.30	36.80	1	1	8.30	48.40
TPSMF4L33A	33	38.70	40.60	1	1	7.50	53.30
TPSMF4L36A	36	40.00	44.20	1	1	8.90	58.10
TPSMF4L40A	40	44.40	49.10	1	1	6.20	64.50
TPSMF4L43A	43	47.80	52.80	1	1	5.80	69.40
TPSMF4L45A	45	50.00	55.30	1	1	5.50	72.70
TPSMF4L48A	48	53.30	58.90	1	1	5.20	77.40
TPSMF4L51A	51	58.70	62.70	1	1	4.90	82.40
TPSMF4L54A	54	80.00	66.30	1	1	4.60	87.10
TPSMF4L58A	58	64.40	71.20	1	1	4.30	93.60
TPSMF4L60A	60	86.70	73.70	1	1	4.10	98.80
TPSMF4L64A	64	71.10	78.60	1	1	3.90	103.00
TPSMF4L70A	70	77.80	88.00	1	1	3.50	113.00
TPSMF4L75A	75	83.30	92.10	1	1	3.30	121.00
TPSMF4L78A	78	86.70	95.80	1	1	3.20	126.00
TPSMF4L85A	85	94.40	104.00	1	1	2.90	137.00

Ratings and Characteristic Curves $T_A=25^\circ\text{C}$ unless otherwise noted

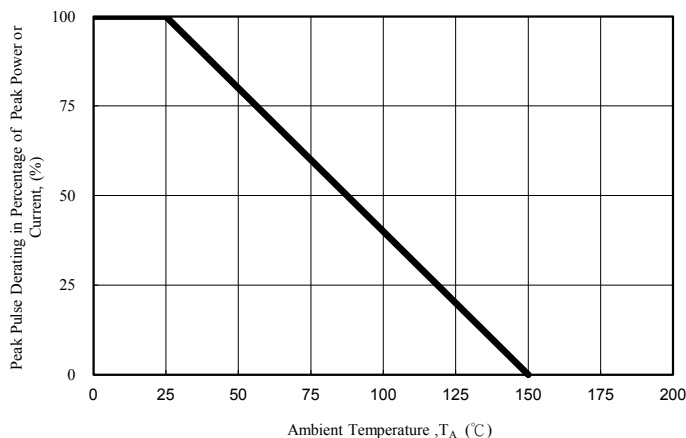


Fig. 1 - Pulse Derating Curve

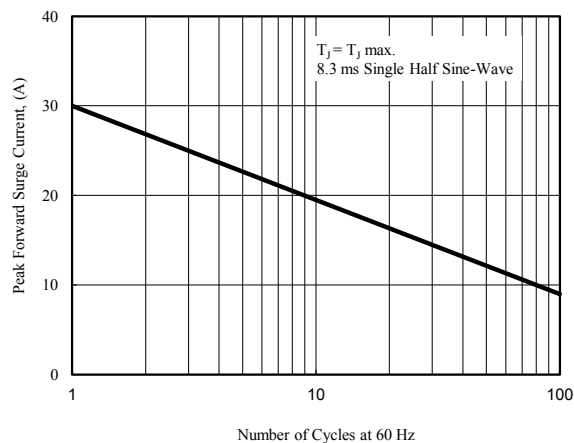


Fig. 2 - Maximum Non-Repetitive

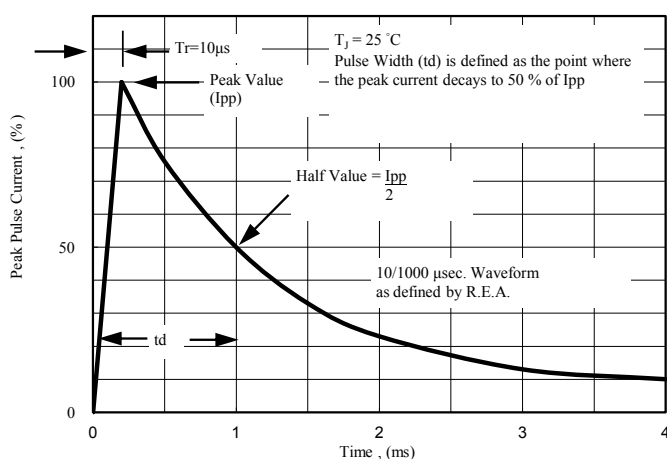


Fig. 3 - Pulse Waveform

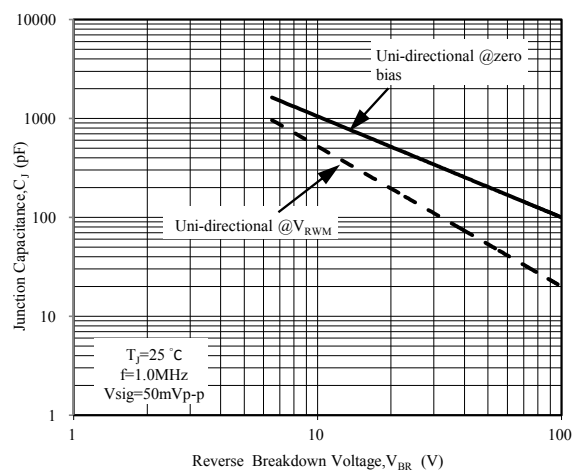


Fig. 4 - Typical Junction Capacitance

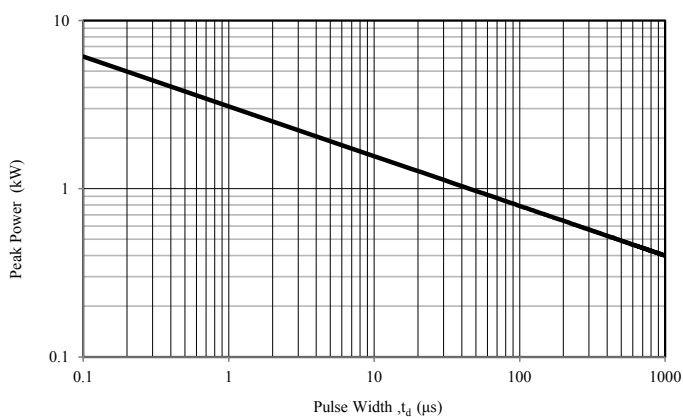


Fig. 5 - Steady State Power Derating Curve